NSN 5961-00-419-4535

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No



View Online at https://aerobasegroup.com/nsn/5961-00-419-4535

Inclosure Material:	
Metal	
Overall Length:	
0.210 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.195 inches	
Internal Configuration:	
Junction contact	
Joint Electronic Device Engineering Council/jedec/case Outline Designa	tion:
To-18	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdow	vn voltage, collector-to-emitter, base open and 5.0 breakdown
voltage, emitter-to-base, collector open	
Current Rating Per Characteristic:	
600.00 milliamperes source cutoff current	
Power Rating Per Characteristic:	
1.8 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: pnp	
Precious Material And Location:	
Leads gold	
Precious Material:	
Gold	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	

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